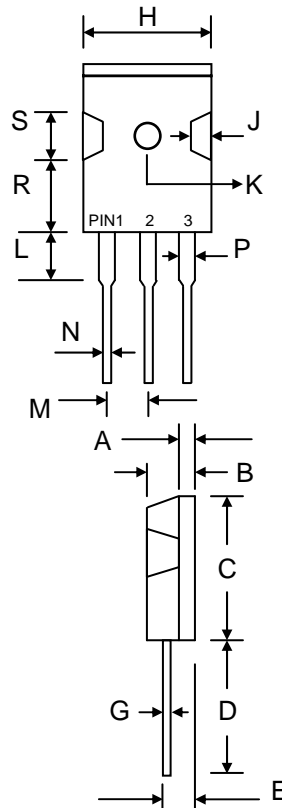


### Features

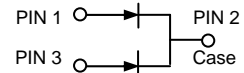
- Schottky Barrier Chip
- Guard Ring for Transient Protection
- Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Current Capability
- Epoxy Meets UL 94V-0 Classification
- Ideally Suited for Use in High Frequency SMPS, Inverters and As Free Wheeling Diodes

### Mechanical Data

- Case: TO-3P, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-750, Method 2026
- Polarity: See Diagram
- Weight: 5.6 grams (approx.)
- Mounting Position: Any
- Mounting Torque: 1.2 N.m Max.
- **Lead Free: For RoHS / Lead Free Version, Add "-LF" Suffix to Part Number, See Page 4**



| TO-3P                |        |        |
|----------------------|--------|--------|
| Dim                  | Min    | Max    |
| A                    | 1.85   | 2.15   |
| B                    | 4.70   | 5.30   |
| C                    | —      | 23.00  |
| D                    | 19.00  | —      |
| E                    | 2.80   | 3.20   |
| G                    | 0.45   | 0.85   |
| H                    | —      | 16.20  |
| J                    | 1.70   | 2.70   |
| K                    | 3.15 Ø | 3.65 Ø |
| L                    | —      | 4.50   |
| M                    | 5.25   | 5.65   |
| N                    | 1.10   | 1.40   |
| P                    | —      | 2.50   |
| R                    | 11.70  | 12.70  |
| S                    | 5.00   | 6.00   |
| All Dimensions in mm |        |        |



### Maximum Ratings and Electrical Characteristics @T<sub>A</sub>=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

| Characteristic                                                                                                        | Symbol                            | S16D 30C    | S16D 35C | S16D 40C | S16D 45C | S16D 50C | S16D 60C | S16D 80C | S16D 100C | Unit |
|-----------------------------------------------------------------------------------------------------------------------|-----------------------------------|-------------|----------|----------|----------|----------|----------|----------|-----------|------|
| Peak Repetitive Reverse Voltage                                                                                       | V <sub>RRM</sub>                  | 30          | 35       | 40       | 45       | 50       | 60       | 80       | 100       | V    |
| Working Peak Reverse Voltage                                                                                          | V <sub>RWM</sub>                  |             |          |          |          |          |          |          |           |      |
| DC Blocking Voltage                                                                                                   | V <sub>R</sub>                    |             |          |          |          |          |          |          |           |      |
| RMS Reverse Voltage                                                                                                   | V <sub>R(RMS)</sub>               | 21          | 25       | 28       | 32       | 35       | 42       | 56       | 70        | V    |
| Average Rectified Output Current<br>@T <sub>C</sub> = 100°C                                                           | I <sub>O</sub>                    | 16<br>8.0   |          |          |          |          |          |          |           | A    |
| Non-Repetitive Peak Forward Surge Current<br>8.3ms Single Half Sine-Wave Superimposed<br>on Rated Load (JEDEC Method) | I <sub>FSM</sub>                  | 200         |          |          |          |          |          |          |           | A    |
| Forward Voltage<br>@I <sub>F</sub> = 8.0A, T <sub>J</sub> = 25°C<br>per diode                                         | V <sub>FM</sub>                   | 0.55        |          | 0.50     |          | 0.75     |          | 0.85     |           | V    |
| Peak Reverse Current<br>At Rated DC Blocking Voltage                                                                  | I <sub>RM</sub>                   | 0.5<br>20   |          |          |          |          |          |          |           | mA   |
| Typical Junction Capacitance (Note 1)                                                                                 | C <sub>J</sub>                    | 500         |          |          |          | 350      |          |          |           | pF   |
| Thermal Resistance Junction to Ambient per diode                                                                      | R <sub>JA</sub>                   | 50          |          |          |          |          |          |          |           | °C/W |
| Thermal Resistance Junction to Case per diode                                                                         | R <sub>JC</sub>                   | 1.5         |          |          |          |          |          |          |           |      |
| Operating and Storage Temperature Range                                                                               | T <sub>J</sub> , T <sub>STG</sub> | -55 to +150 |          |          |          |          |          |          |           | °C   |

Note: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

# S16D30C – S16D100C

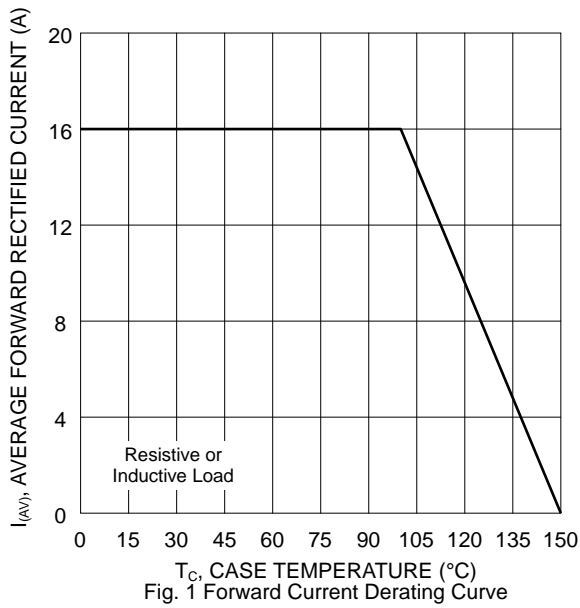


Fig. 1 Forward Current Derating Curve

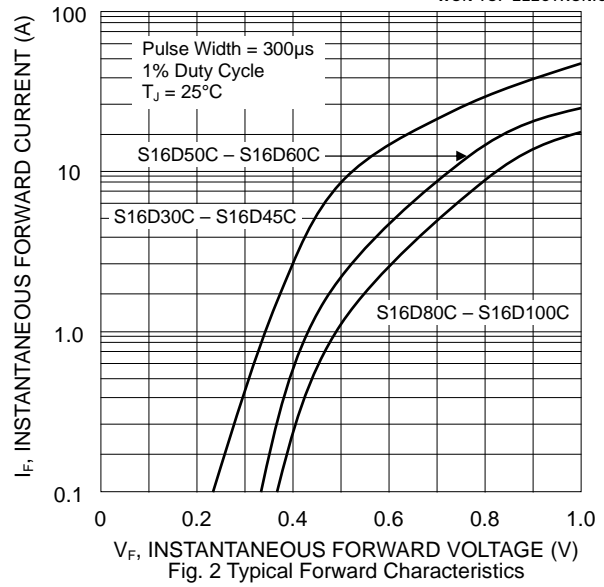


Fig. 2 Typical Forward Characteristics

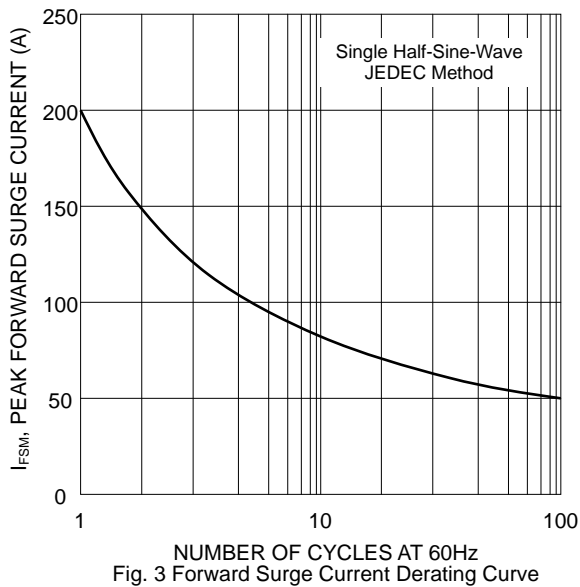


Fig. 3 Forward Surge Current Derating Curve

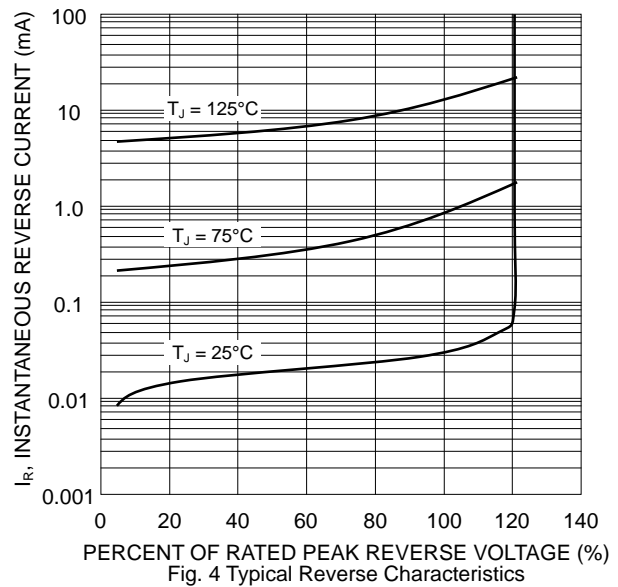


Fig. 4 Typical Reverse Characteristics

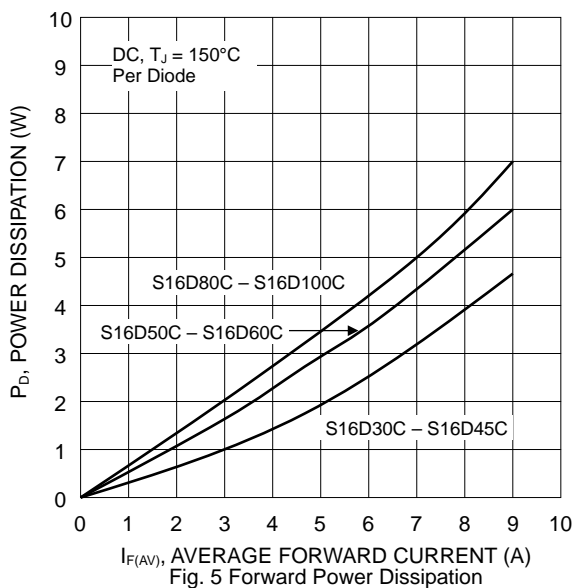


Fig. 5 Forward Power Dissipation

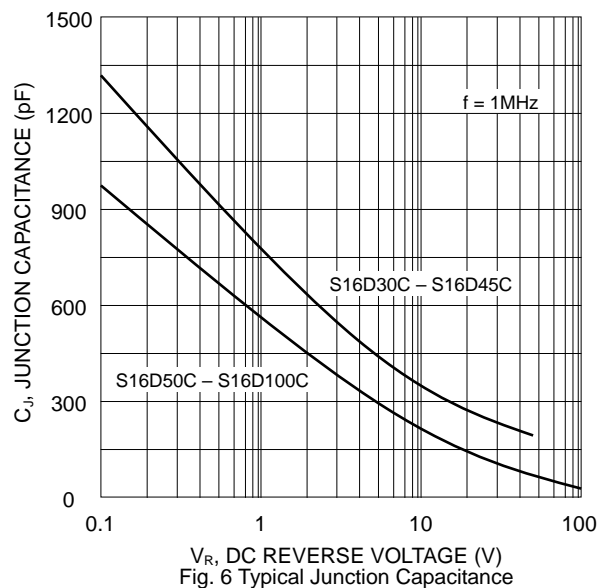
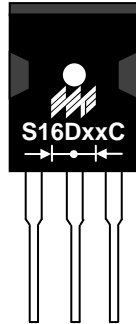


Fig. 6 Typical Junction Capacitance

## MARKING INFORMATION



S16DxxC = Device Number  
 xx = 30, 35, 40, 45, 50, 60, 80 or 100  
 Polarity = As Marked on Body

## PACKAGING INFORMATION

### BULK

| Tube Size<br>L x W x H (mm) | Quantity<br>(PCS) | Inner Box Size<br>L x W x H (mm) | Quantity<br>(PCS) | Carton Size<br>L x W x H (mm) | Quantity<br>(PCS) | Approx. Gross Weight<br>(KG) |
|-----------------------------|-------------------|----------------------------------|-------------------|-------------------------------|-------------------|------------------------------|
| 505 x 46 x 6.5              | 30                | 520 x 145 x 95                   | 1,200             | 540 x 306 x 115               | 2,400             | 18.0                         |

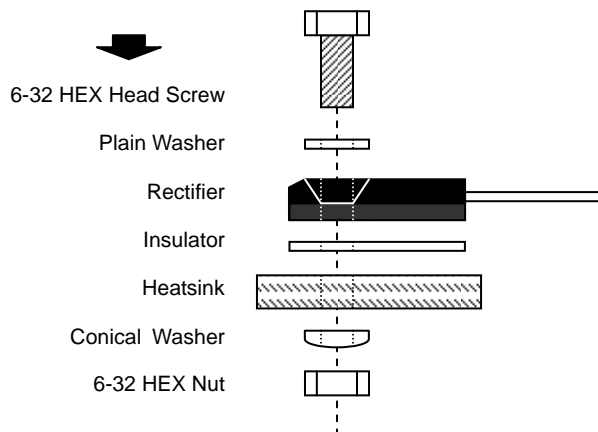
**Note:** 1. Anti-static tube, water clear color.

## RECOMMENDED SCREW MOUNTING ARRANGEMENT

Recommended isolated mounting when screw is at heatsink potential. 6-32 hardware is used.

A conical washer should be used to apply proper force to the device. Screw should not be tightened with any type of air-forced torque or equipment that may cause high impact on device package.

The interface should apply a layer of thermal grease or a highly conductive thermal pad for better heat dissipation.



## ORDERING INFORMATION

| Product No. | Package Type | Shipping Quantity |
|-------------|--------------|-------------------|
| S16D30C     | TO-3P        | 30 Units/Tube     |
| S16D35C     | TO-3P        | 30 Units/Tube     |
| S16D40C     | TO-3P        | 30 Units/Tube     |
| S16D45C     | TO-3P        | 30 Units/Tube     |
| S16D50C     | TO-3P        | 30 Units/Tube     |
| S16D60C     | TO-3P        | 30 Units/Tube     |
| S16D80C     | TO-3P        | 30 Units/Tube     |
| S16D100C    | TO-3P        | 30 Units/Tube     |

1. Shipping quantity given is for minimum packing quantity only. For minimum order quantity, please consult the Sales Department.
2. **To order RoHS / Lead Free version (with Lead Free finish), add "-LF" suffix to part number above. For example, S16D30C-LF.**

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**WARNING:** DO NOT USE IN LIFE SUPPORT EQUIPMENT. WTE power semiconductor products are not authorized for use as critical components in life support devices or systems without the express written approval.

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**Internet:** http://www.wontop.com

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